

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_b
20V	23mΩ@4.5V	5A
	27mΩ@2.5V	

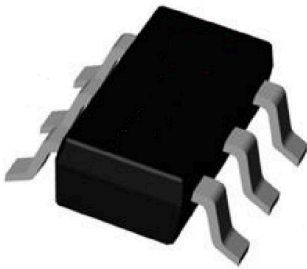
Feature

- Advanced trench process technology
- High density cell design for ultra low on-resistance

Application

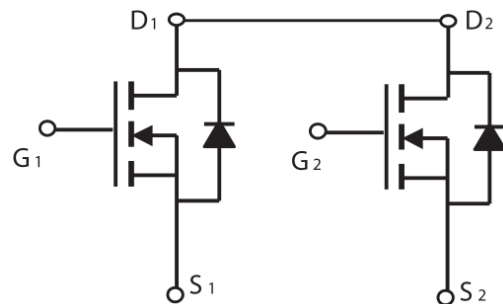
- Battery protection
- Switching application

Package

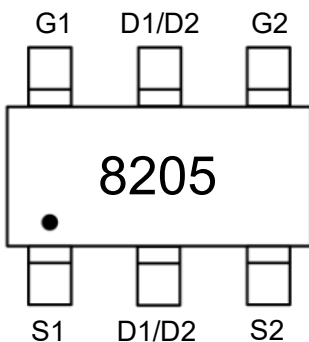


SOT-23-6L

Circuit diagram



Marking



Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current	I_D	5	A
Pulsed Drain Current	I_{DM}	25	A
Power Dissipation	P_D	1.5	W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 ~ +150	°C

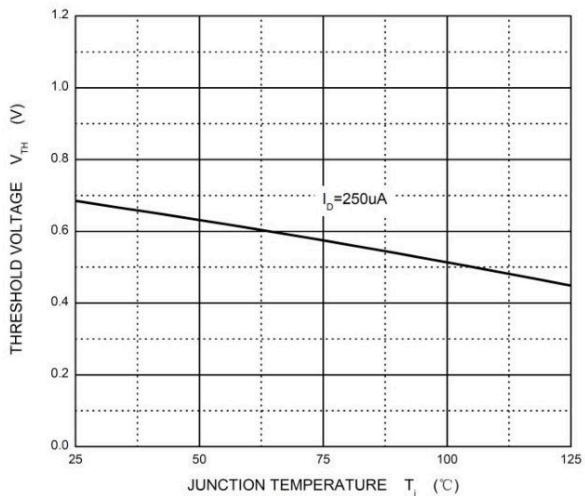
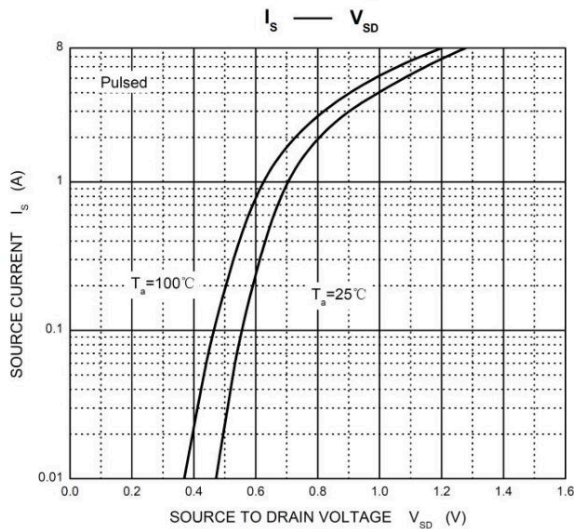
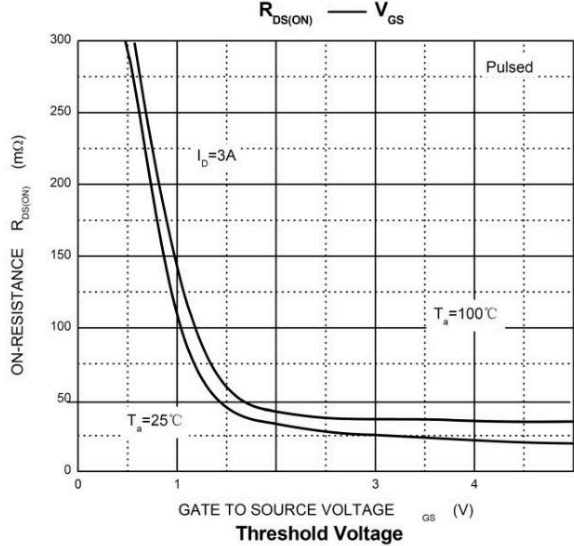
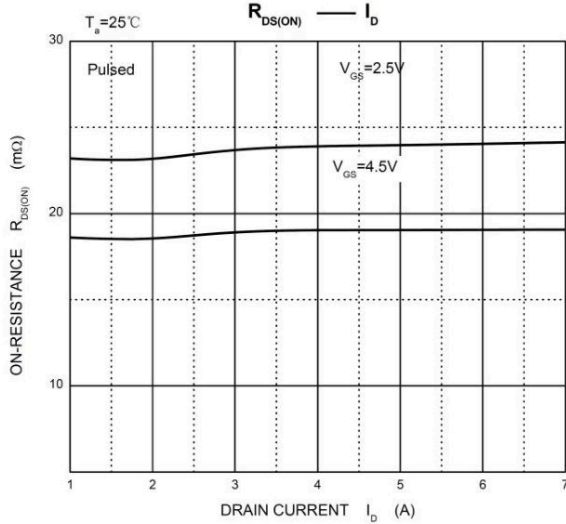
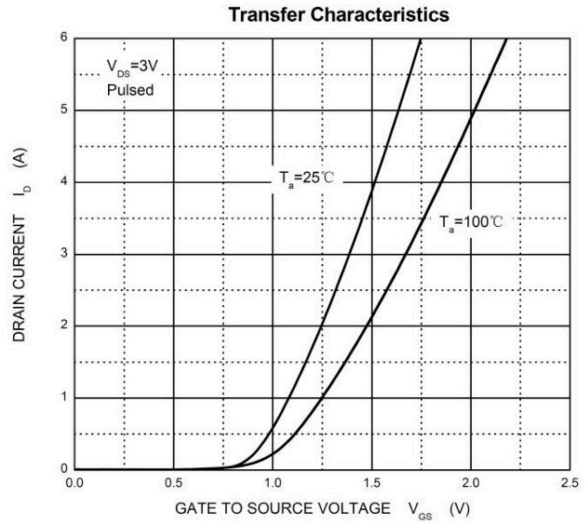
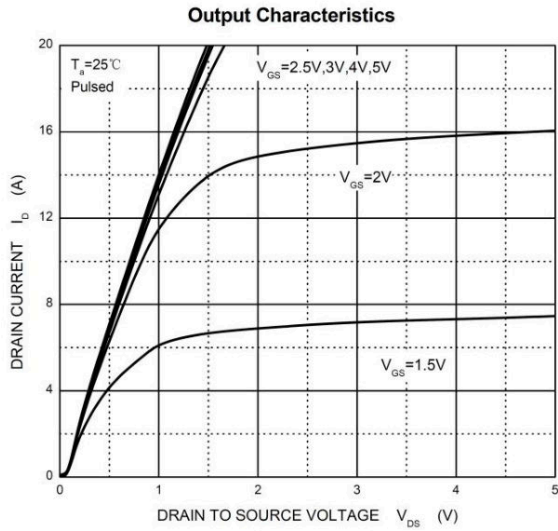
Electrical characteristics (T_A=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 12V, V_{DS} = 0V$			±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.5		1.2	V
Drain-source on-resistance ¹⁾	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 4.5A$		18	23	mΩ
		$V_{GS} = 2.5V, I_D = 3.5A$		23	27	
Forward transconductance ¹⁾	g_{FS}	$V_{DS} = 5V, I_D = 7A$	9			S
Dynamic characteristics²⁾						
Input Capacitance	C_{iss}	$V_{DS} = 8V, V_{GS} = 0V, f = 1MHz$		800		pF
Output Capacitance	C_{oss}			155		
Reverse Transfer Capacitance	C_{rss}			125		
Total Gate Charge	Q_g	$V_{DS} = 10V, V_{GS} = 4.5V, I_D = 4A$		11		nC
Gate-Source Charge	Q_{gs}			2.3		
Gate-Drain Charge	Q_{gd}			2.5		
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 10V, V_{GS} = 4V, I_D = 1A, R_{GEN} = 10\Omega$		18		nS
Turn-on rise time	t_r			5		
Turn-off delay time	$t_{d(off)}$			43		
Turn-off fall time	t_f			20		
Source-Drain Diode characteristics						
Diode Forward voltage	V_{DS}	$V_{GS} = 0V, I_S = 1.7A$			1.2	V

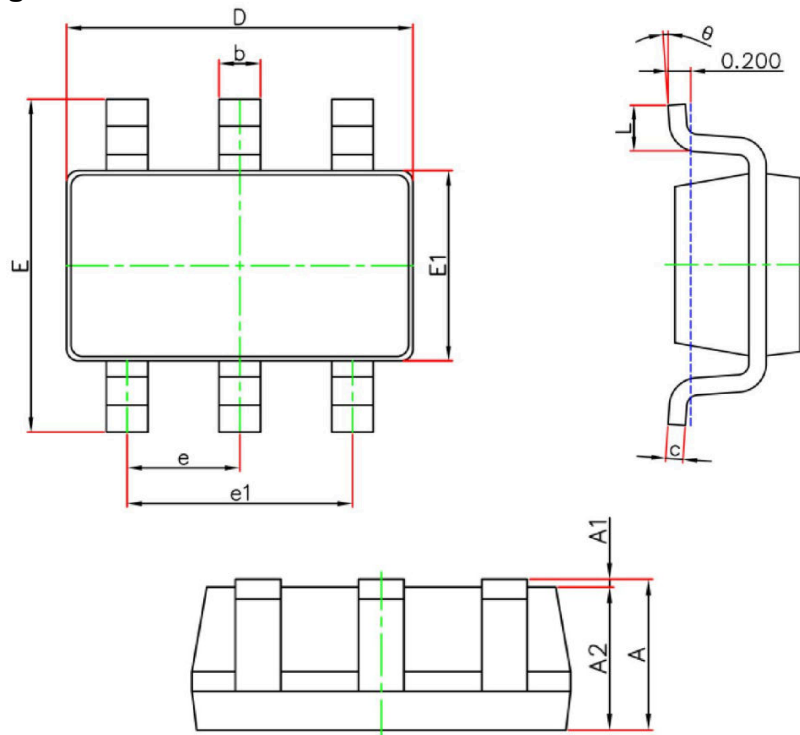
Notes:

- 1) Pulse Test: Pulse Width < 300μs, Duty Cycle ≤2%.
- 2) Guaranteed by design, not subject to production testing.

Typical Characteristics



SOT-23-6L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	2.650	2.950	0.104	0.116
E1	1.500	1.700	0.059	0.067
e	0.950 (BSC)		0.037 (BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°